NSN 5961-00-103-7898

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-103-7898 **Inclosure Material:** Metal **Overall Length:** Between 0.155 inches and 0.185 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 40.0 breakdown voltage, collector-to-emitter, base open all transistor and 60.0 collector to base voltage, dc all transistor and 5.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 600.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** 2nd transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No